

MPSL01



NPN General Purpose Amplifier

This device is designed for general purpose, high voltage amplifiers and gas discharge display driving. Sourced from Process 16. See 2N5551 for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	120	V
V _{CBO}	Collector-Base Voltage	140	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		MPSL01	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/∘C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_{C} = 1.0 \text{mA}, I_{B} = 0$	120		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	140		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	V _{CB} = 75 V, I _E = 0		1.0	μΑ
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 4.0 \text{ V}, I_{C} = 0$		100	nA
ON CHAF	RACTERISTICS*				
		LV - 50V L - 40 m	T 50	200	
h _{FE}	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$	50	300	l v
h _{FE}		I _C = 10 mA, I _B = 1.0 mA	50	300 0.2 0.3	V
h _{FE} V _{CE(sat)}	DC Current Gain	I _C = 10 mA, I _B = 1.0 mA I _C = 50 mA, I _B = 5.0 mA I _C = 10 mA, I _B = 1.0 mA	50	0.2	1 '
h _{FE} V _{CE(sat)}	DC Current Gain Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA I _C = 50 mA, I _B = 5.0 mA	50	0.2 0.3	V
h_{FE} $V_{CE(sat)}$ $V_{BE(sat)}$	DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage IGNAL CHARACTERISTICS	I_{C} = 10 mA, I_{B} = 1.0 mA I_{C} = 50 mA, I_{B} = 5.0 mA I_{C} = 10 mA, I_{B} = 1.0 mA I_{C} = 50 mA, I_{B} = 5.0 mA	50	0.2 0.3 1.2 1.4	V V V
h_{FE} $V_{CE(sat)}$ $V_{BE(sat)}$ SMALL S	DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA I _C = 50 mA, I _B = 5.0 mA I _C = 10 mA, I _B = 1.0 mA	50	0.2 0.3 1.2	V
h_{FE} $V_{CE(sat)}$ $V_{BE(sat)}$	DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage IGNAL CHARACTERISTICS	I_{C} = 10 mA, I_{B} = 1.0 mA I_{C} = 50 mA, I_{B} = 5.0 mA I_{C} = 10 mA, I_{B} = 1.0 mA I_{C} = 50 mA, I_{B} = 5.0 mA	30	0.2 0.3 1.2 1.4	V V V

^{*}Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

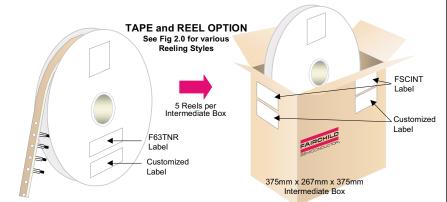
TO-92 Tape and Reel Data



TO-92 Packaging Configuration: Figure 1.0







TO-92 TNR/AMMO PACKING INFROMATION

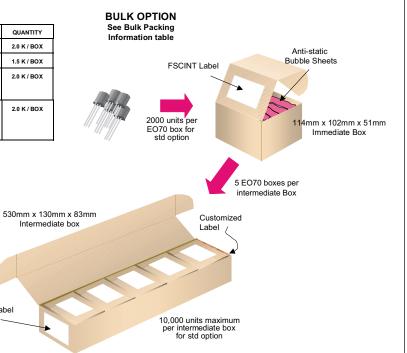
Packing	Style	Quantity	EOL code
Reel	Α	2,000	D26Z
	E	2,000	D27Z
Ammo	M	2,000	D74Z
	Р	2,000	D75Z

Unit weight = 0.22 gm
Reel weight with components = 1.04 kg
Ammo weight with components = 1.02 kg
Max quantity per intermediate box = 10,000 units



(TO-92) BULK PACKING INFORMATION

EOL CODE	DESCRIPTION	LEADCLIP DIMENSION	QUANTITY
J18Z	TO-18 OPTION STD	NO LEAD CLIP	2.0 K / BOX
J05Z	TO-5 OPTION STD	NO LEAD CLIP	1.5 K / BOX
NO EOL CODE	TO-92 STANDARD STRAIGHT FOR: PKG 92, 94 (NON PROELECTRON SERIES), 96	NO LEADCLIP	2.0 K / BOX
L34Z	TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98	NO LEADCLIP	2.0 K / BOX

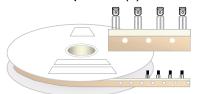


FSCINT Label

TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

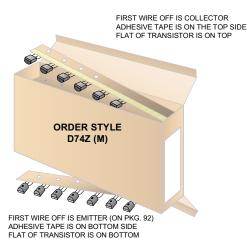


Style "A", D26Z, D70Z (s/h)

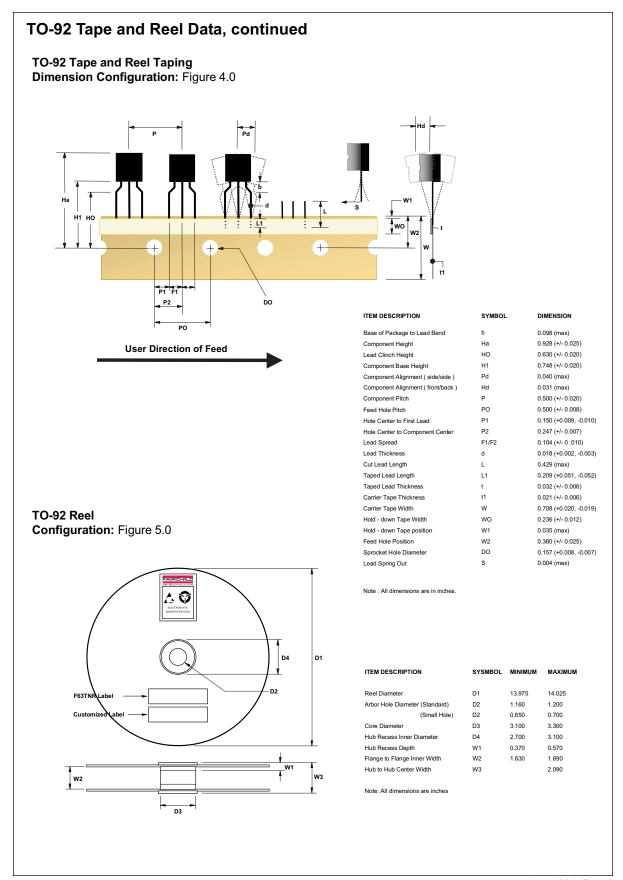
Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





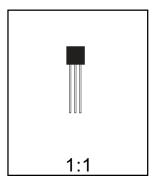


TO-92 Package Dimensions



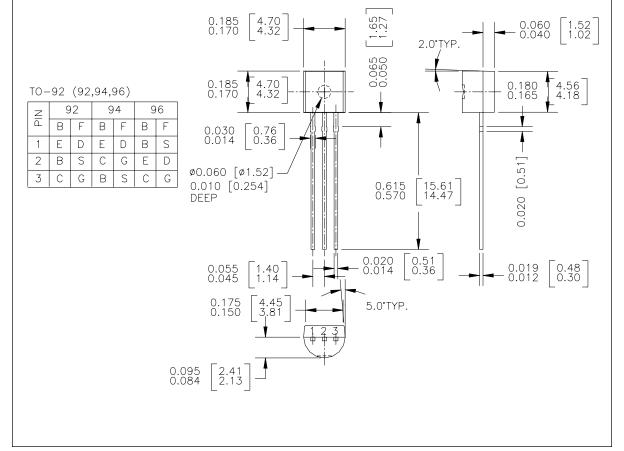
TO-92 (FS PKG Code 92, 94, 96)





Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



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